

MOSFETs Silicon N-Channel MOS (U-MOSVII-H)

TPCA8064-H

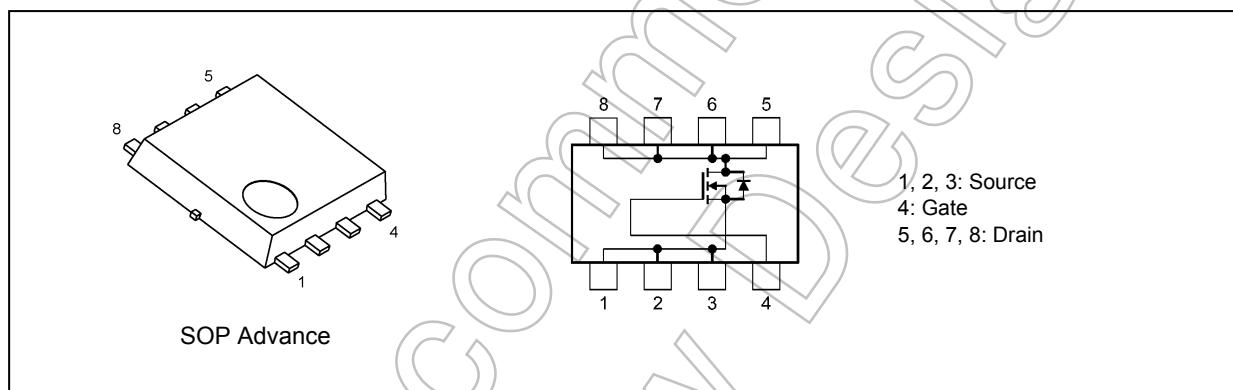
1. Applications

- High-Efficiency DC-DC Converters
- Notebook PCs
- Mobile Equipment

2. Features

- (1) Small footprint due to a small and thin package
- (2) High-speed switching
- (3) Small gate charge: $Q_{SW} = 5.0 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 7.9 \text{ m}\Omega$ (typ.) ($V_{GS} = 4.5 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \mu\text{A}$ (max) ($V_{DS} = 30 \text{ V}$)
- (6) Enhancement mode: $V_{th} = 1.3$ to 2.3 V ($V_{DS} = 10 \text{ V}$, $I_D = 0.2 \text{ mA}$)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	30	V
Gate-source voltage	V_{GSS}	± 20	
Drain current (DC)	I_D	20	A
Drain current (pulsed)	I_{DP}	60	
Power dissipation ($T_c = 25 \text{ }^\circ\text{C}$)	P_D	32	W
Power dissipation ($t = 10 \text{ s}$) (Note 2)	P_D	2.8	W
Power dissipation ($t = 10 \text{ s}$) (Note 3)	P_D	1.6	W
Single-pulse avalanche energy	E_{AS}	104	mJ
Avalanche current	I_{AR}	20	A
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Start of commercial production

2010-04

5. Thermal Characteristics

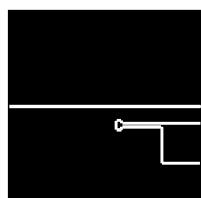
Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance ($T_c = 25^\circ\text{C}$)	$R_{th(ch-c)}$	3.91	°C/W
Channel-to-ambient thermal resistance ($t = 10\text{ s}$) (Note 2)	$R_{th(ch-a)}$	44.6	°C/W
Channel-to-ambient thermal resistance ($t = 10\text{ s}$) (Note 3)	$R_{th(ch-a)}$	78.1	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

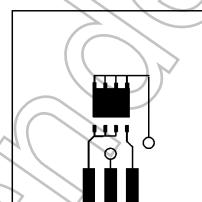
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: $V_{DD} = 24\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.2\text{ mH}$, $R_G = 1\text{ }\Omega$, $I_{AR} = 20\text{ A}$



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	30	—	—	
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	15	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}, I_D = 0.2\text{ mA}$	1.3	—	2.3	
Drain-source on-resistance	$R_{DS(\text{ON})}$	$V_{GS} = 4.5\text{ V}, I_D = 10\text{ A}$	—	7.9	10.6	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}, I_D = 10\text{ A}$	—	5.8	8.2	

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1600	1900	pF
Reverse transfer capacitance	C_{rss}		—	78	120	
Output capacitance	C_{oss}		—	290	—	
Gate resistance	r_g	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 5\text{ MHz}$	—	1.4	2.1	Ω
Switching time (rise time)	t_r	See Fig. 6.2.1.	—	3.4	—	ns
Switching time (turn-on time)	t_{on}		—	9.2	—	
Switching time (fall time)	t_f		—	5.9	—	
Switching time (turn-off time)	t_{off}		—	24	—	

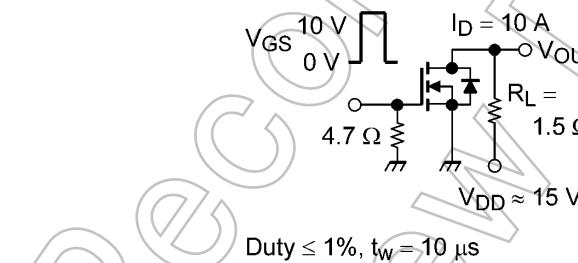


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 20\text{ A}$	—	23	—	nC
		$V_{DD} \approx 24\text{ V}, V_{GS} = 5\text{ V}, I_D = 20\text{ A}$	—	11	—	
Gate-source charge 1	Q_{gs1}	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 20\text{ A}$	—	5.1	—	
Gate-drain charge	Q_{gd}		—	2.5	—	
Gate switch charge	Q_{sw}		—	5.0	—	

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 5)	I_{DRP}	—	—	—	60	A
Diode forward voltage	V_{DSF}	$I_{DR} = 20\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V

Note 5: Ensure that the channel temperature does not exceed 150 °C.

7. Marking

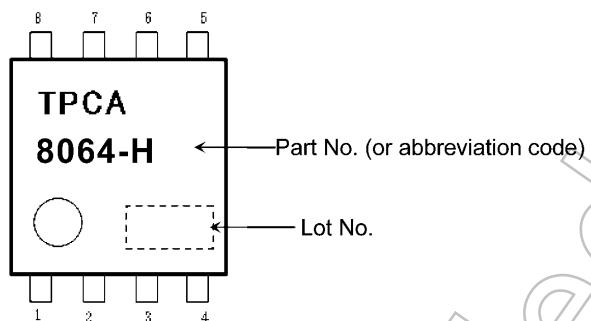


Fig. 7.1 Marking

Not Recommended
for New Design

8. Characteristics Curves (Note)

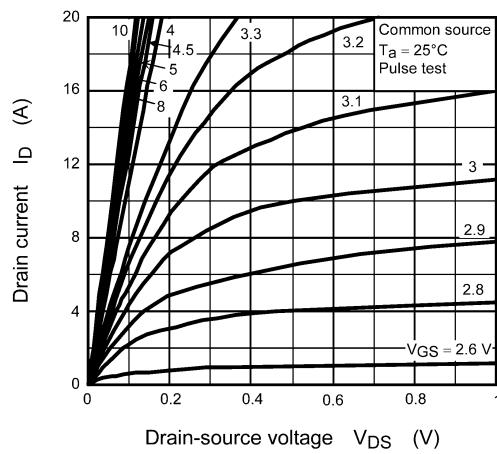


Fig. 8.1 I_D - V_{DS}

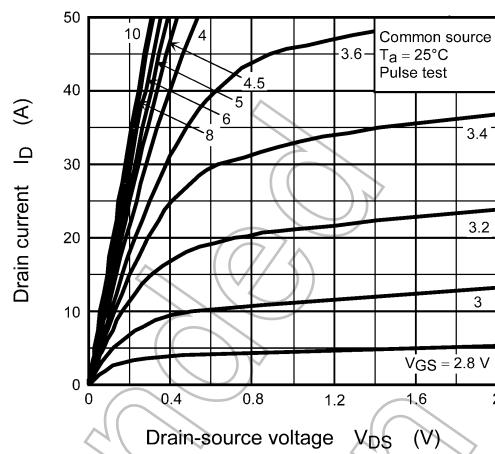


Fig. 8.2 I_D - V_{DS}

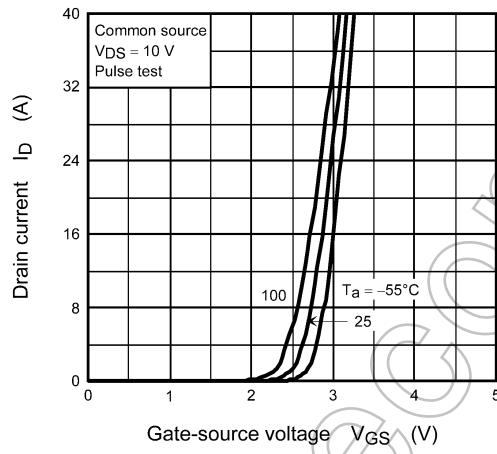


Fig. 8.3 I_D - V_{GS}

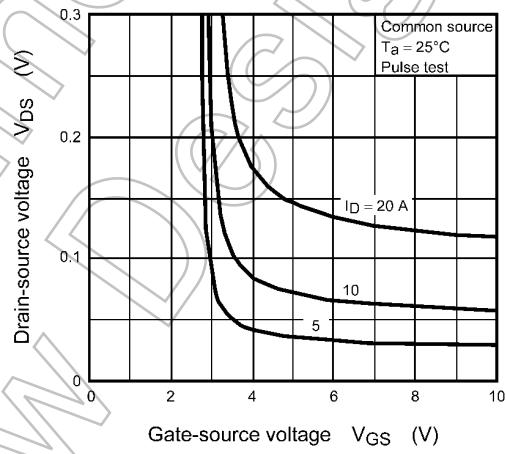


Fig. 8.4 V_{DS} - V_{GS}

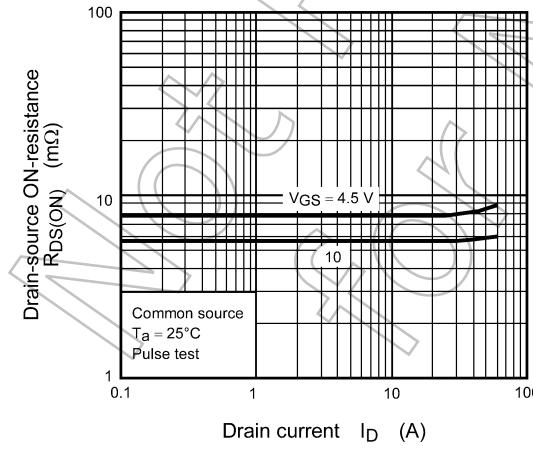


Fig. 8.5 $R_{DS(ON)}$ - I_D

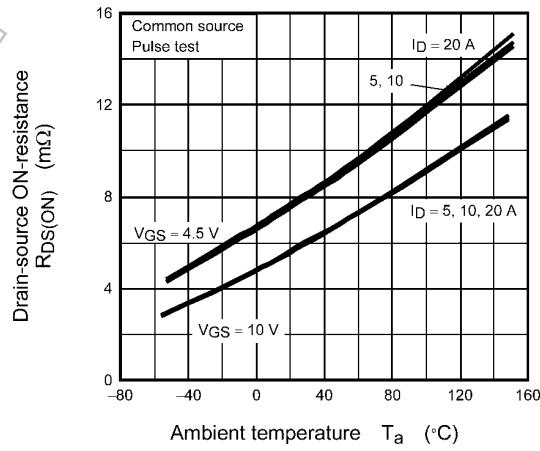


Fig. 8.6 $R_{DS(ON)}$ - T_a

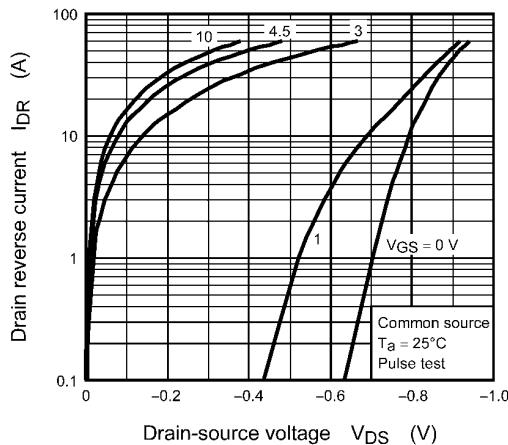
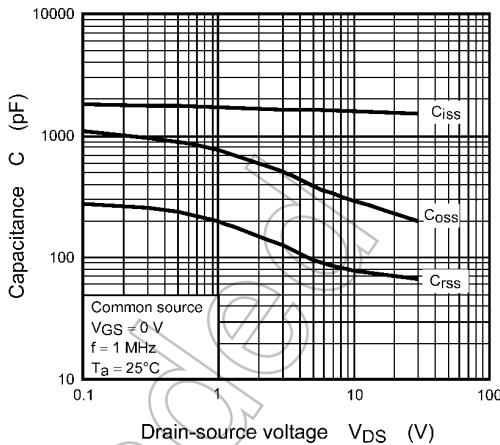
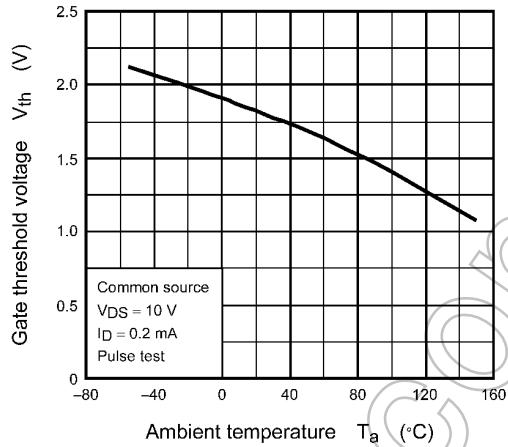
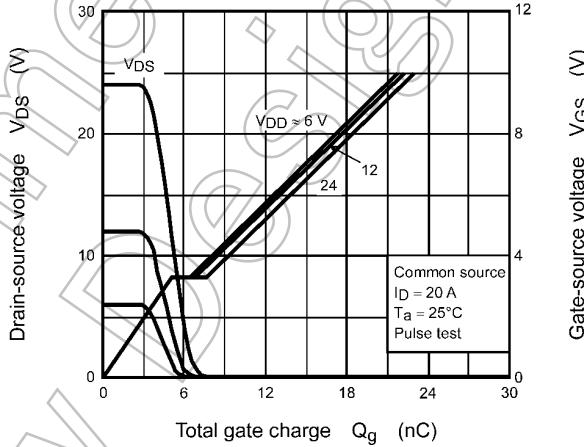
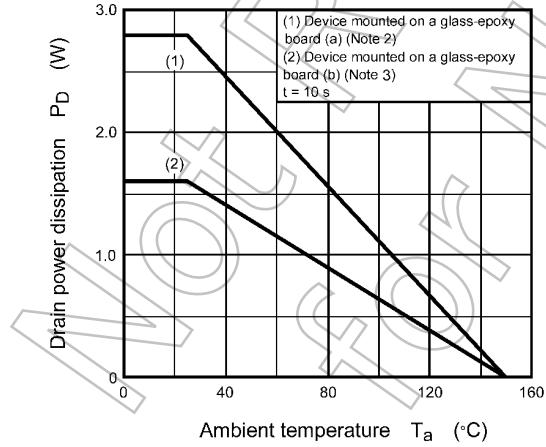
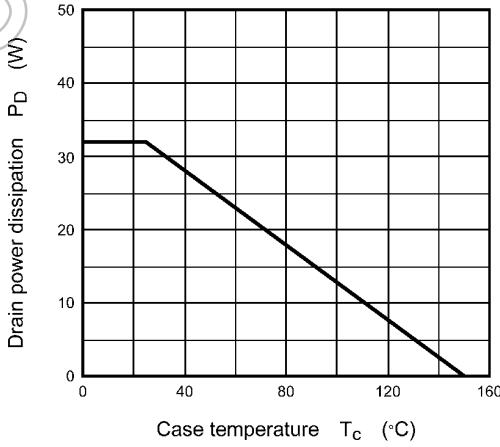
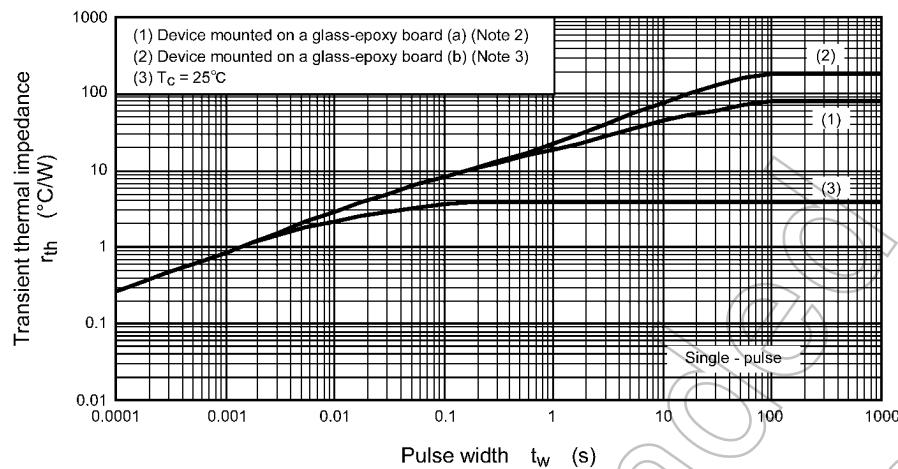
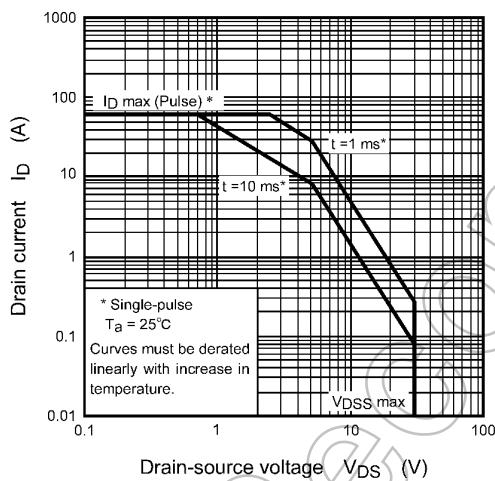
Fig. 8.7 I_{DR} - V_{DS} Fig. 8.8 Capacitance - V_{DS} Fig. 8.9 V_{th} - T_a 

Fig. 8.10 Dynamic Input/Output Characteristics

Fig. 8.11 P_D - T_a
(Guaranteed Maximum)Fig. 8.12 P_D - T_c
(Guaranteed Maximum)



**Fig. 8.13 r_{th} - t_w
(Guaranteed Maximum)**

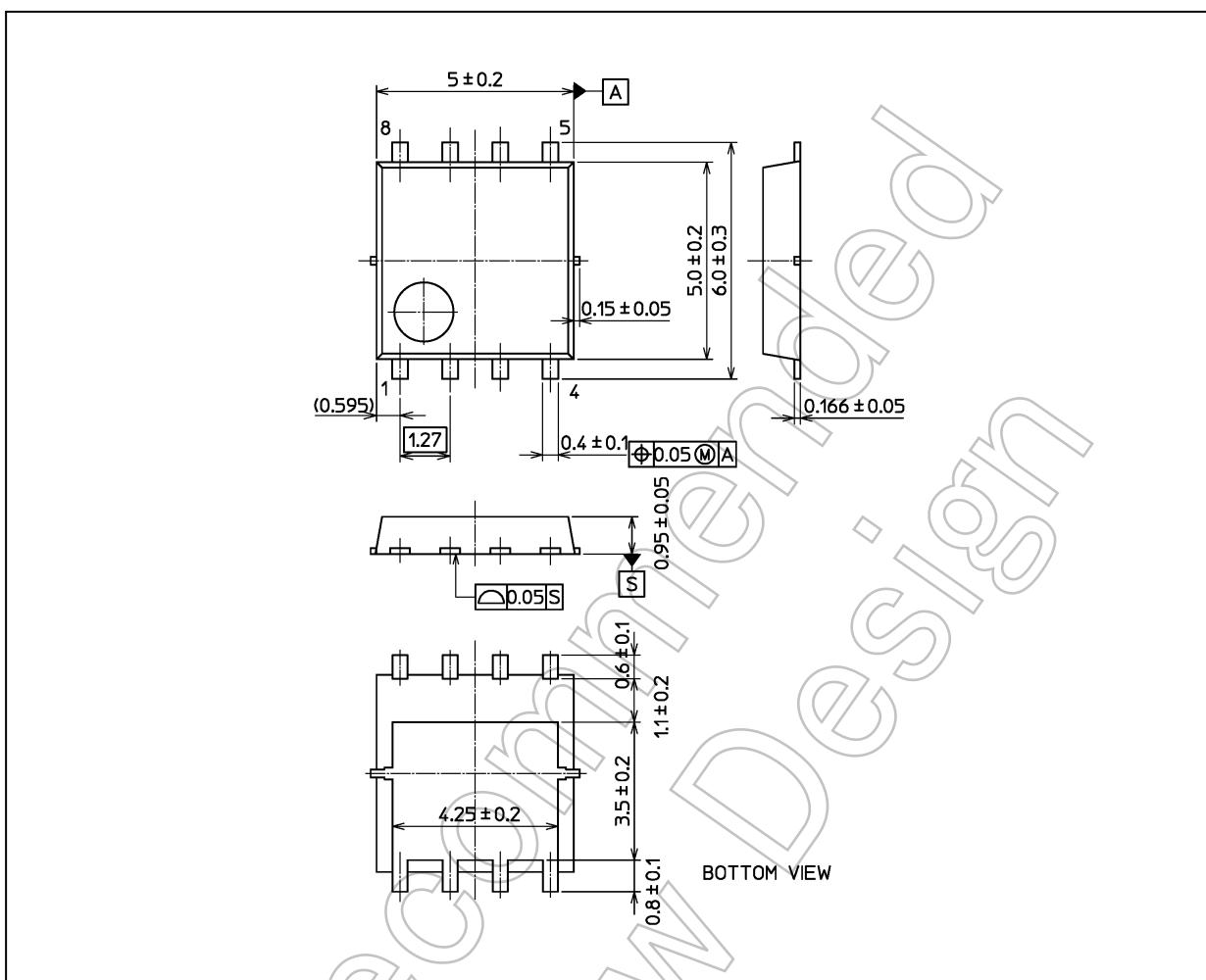


**Fig. 8.14 Safe Operating Area
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q1S
Nickname: SOP Advance

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